



N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)			
30	0.003 at V _{GS} = 10 V	25			
	0.004 at V _{GS} = 4.5 V	22			

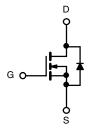
FEATURES

- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET[®] Gen II
- Ultra Low On-Resistance Using High Density TrenchFET Power MOSFET Technology



APPLICATIONS

- · Synchronous Buck Low-Side
 - Notebook
 - Server
 - Workstation
- Synchronous Rectifier-POL



N-Channel MOSFET

		SO-8		
s	1		8	D
s	2		7	D
S	3		6	D
G	4		5	D
		Top View	1	

Ordering Information: Si4320DY-T1-E3 (Lead (Pb)-free)

Si4320DY-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted					
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	30		V
Gate-Source Voltage		V _{GS}	± 20		
Continuous Dunin Courset /T 450 90\8	T _A = 25 °C	I_	25	17	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C	- I _D	20	13	
Pulsed Drain Current (10 μs Pulse Width)		I _{DM}	70		Α
Continuous Source Current (Diode Conduction) ^a		I _S	2.9	1.3	
Avalanche Current		I _{AS}	50		
W . D D	T _A = 25 °C	P _D	3.5 1.6		W
Maximum Power Dissipation ^a	T _A = 70 °C] ' ['] D	2.2	1	۷V
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^a	t ≤ 10 s	R_{thJA}	29	35	
Maximum Junction-to-Ambient	Steady State	' 'thJA	67	80	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	13	16	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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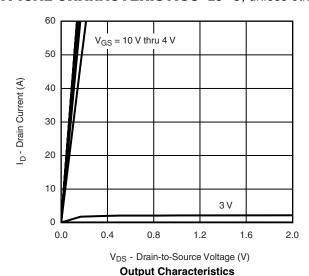
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.0		3.0	V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA
Zero Gate Voltage Drain Current	lasa	V _{DS} = 30 V, V _{GS} = 0 V			1	
Zeio Gale Vollage Dialii Guireili	I _{DSS}	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			5	μΑ
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α
D : 0	D	V _{GS} = 10 V, I _D = 25 A		0.0024	0.003	Ω
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 22 \text{ A}$		0.0032	0.004	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 25 A		110		S
Diode Forward Voltage ^a	V_{SD}	I _S = 2.9 A, V _{GS} = 0 V		0.72	1.1	V
Dynamic ^b						
Input Capacitance	C _{iss}			6500		
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 20 \text{ A}$		930		pF
Reverse Transfer Capacitance	C _{rss}			610		
Total Gate Charge Q _g				45	70	
Gate-Source Charge	Q _{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 20 \text{ A}$		20		nC
Gate-Drain Charge	Q_{gd}			16		
Gate Resistance	R _g f = 1.0 MHz			1.1		Ω
Turn-On Delay Time	t _{d(on)}			27	40	
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		21	35	ns
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ 1 A, V_{GEN} = 10 V, R_g = 6 Ω		107	160	
Fall Time	t _f			43	65	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.9 A, dI/dt = 100 A/μs		45	70	

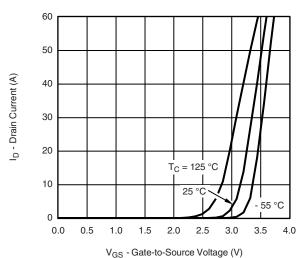
Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





VGS - date-to-source voltage (v

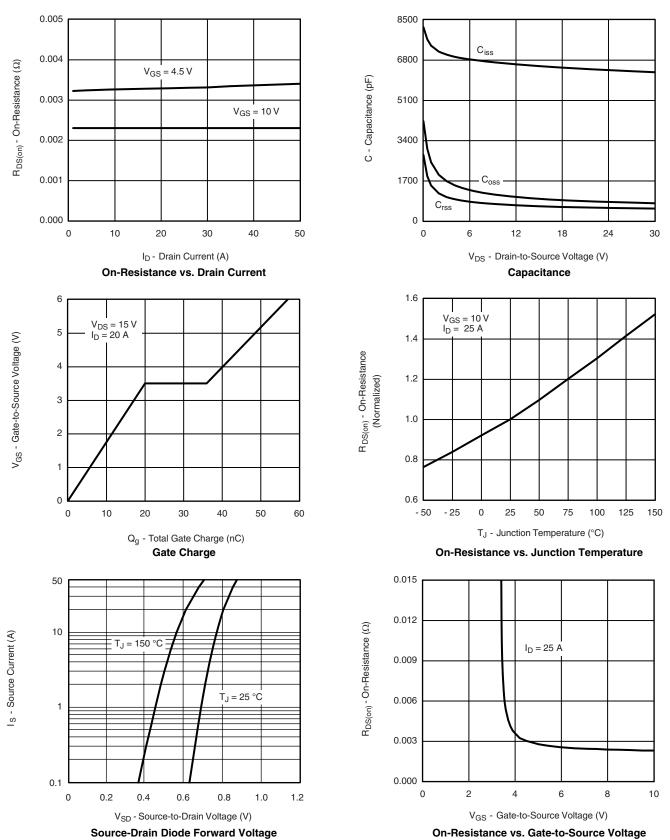
Transfer Characteristics







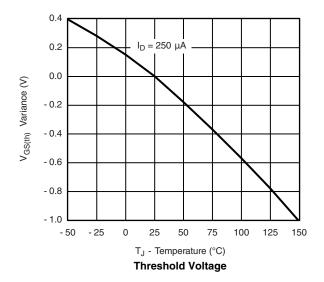
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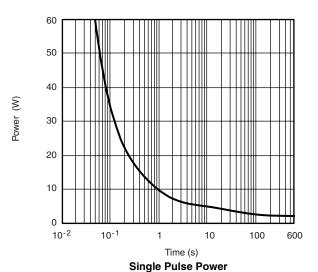


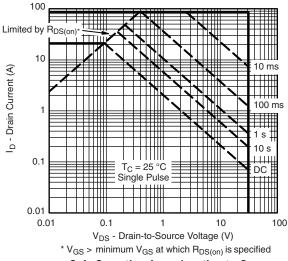
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



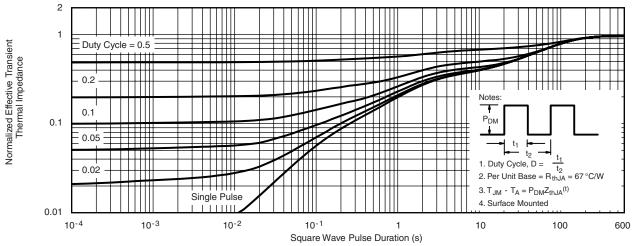




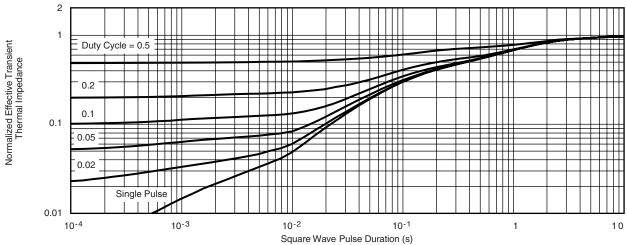
Safe Operating Area, Junction-to-Case



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Ambient

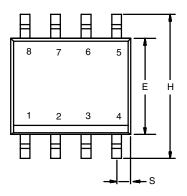


Normalized Thermal Transient Impedance, Junction-to-Foot

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SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







	MILLIMETERS INCHES			HES		
DIM	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
E	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
Н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
FCN: C-06527-Bey 11-Sen-06						

DWG: 5498

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RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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